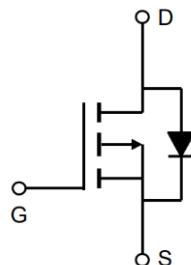


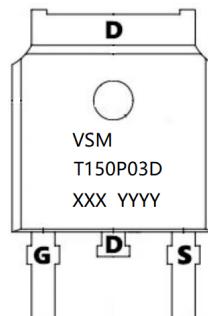
General Features

V _{DS}	I _D	R _{DSON} Type @ V _{GS} = -10V	R _{DSON} Type @ V _{GS} = -4.5V
- 30V	- 30A	15 mΩ	23 mΩ



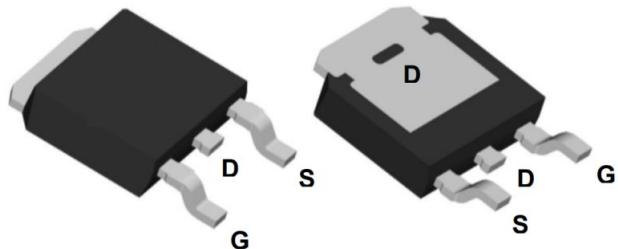
Description

The VSMT150P03DA1 uses advanced trench technology to provide excellent R_{DSON}, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



Application

- Lithium battery protection
- Wireless impact
- Mobile phone fast charging



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
VSMT150P03DA1	TO-252-3L	VSM T150P03D XXX YYYY	2500

Absolute Maximum Ratings (TC=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	-30	V
V _{GS}	Gate-Source Voltage	±20	V
I _D @TC=25°C	Continuous Drain Current, V _{GS} @ -10V1	-30	A
I _D @TC=100°C	Continuous Drain Current, V _{GS} @ -10V1	-20	A
I _{DM}	Pulsed Drain Current2	-68	A
E _{AS}	Single Pulse Avalanche Energy3	125	mJ
P _D @TC=25°C	Total Power Dissipation4	29	W
T _{TG}	Storage Temperature Range	-55 to 150	°C
T _J	Operating Junction Temperature Range	-55 to 150	°C
R _{θJA}	Thermal Resistance Junction-Ambient 1	62.5	°C/W
R _{θJC}	Thermal Resistance Junction-Case1	3.6	°C/W

Electrical Characteristics ($T_J=25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V(BR)DSS	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}, I_D= -250\mu\text{A}$	-30	-33	-	V
IDSS	Zero Gate Voltage Drain Current	$V_{DS}=-30\text{V}, V_{GS}=0\text{V},$	-	-	-1	μA
IGSS	Gate to Body Leakage Current	$V_{DS}=0\text{V}, V_{GS}= \pm 20\text{V}$	-	-	± 100	nA
VGS(th)	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D= -250\mu\text{A}$	-1.2	-1.5	-2.5	V
RDS(on)	Static Drain-Source on-Resistance note3	$V_{GS}= -10\text{V}, I_D= -10\text{A}$	-	15	20	$\text{m}\Omega$
		$V_{GS}= -4.5\text{V}, I_D= -5\text{A}$	-	23	30	
Ciss	Input Capacitance	$V_{DS}= -15\text{V}, V_{GS}=0\text{V}, f=1.0\text{MHz}$	-	1250	-	pF
Coss	Output Capacitance		-	327	-	pF
Crss	Reverse Transfer Capacitance		-	278	-	pF
Qg	Total Gate Charge	$V_{DS}= -15\text{V}, I_D= -9.1\text{A}, V_{GS}= -10\text{V}$	-	30	-	nC
Qgs	Gate-Source Charge		-	5.3	-	nC
Qgd	Gate-Drain("Miller") Charge		-	7.6	-	nC
td(on)	Turn-on Delay Time	$V_{DD}= -15\text{V}, I_D= -6\text{A}, V_{GS}= -10\text{V}, R_{GEN}=2.5\Omega$	-	14	-	ns
tr	Turn-on Rise Time		-	20	-	ns
td(off)	Turn-off Delay Time		-	95	-	ns
tf	Turn-off Fall Time		-	65	-	ns
IS	Maximum Continuous Drain to Source Diode Forward Current		-	-	-10	A
ISM	Maximum Pulsed Drain to Source Diode Forward Current		-	-	-40	A
VSD	Drain to Source Diode Forward Voltage	$V_{GS}=0\text{V}, I_S= -11\text{A}$	-	-0.8	-1.2	V

Note :

1. The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
2. The data tested by pulsed , pulse width $\leq 300\text{us}$, duty cycle $\leq 2\%$
3. The power dissipation is limited by 150°C junction temperature
4. The data is theoretically the same as ID and IDM , in real applications , should be limited by total power dissipation.

Typical Characteristics

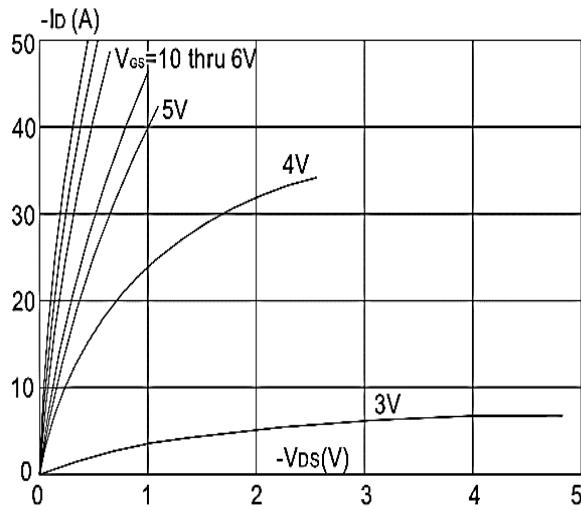


Figure 1: Output Characteristics

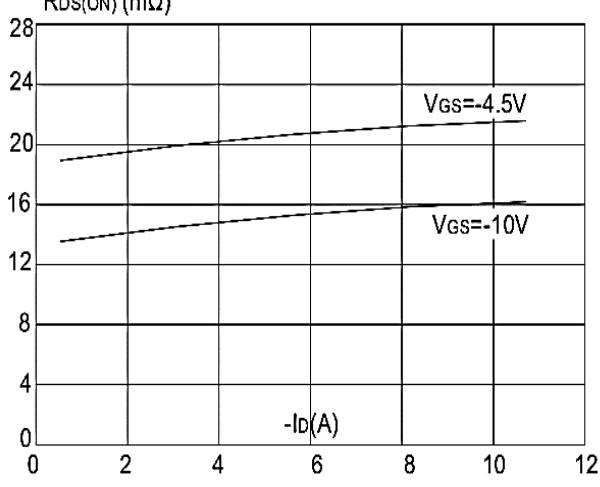


Figure 3: On-resistance vs. Drain Current

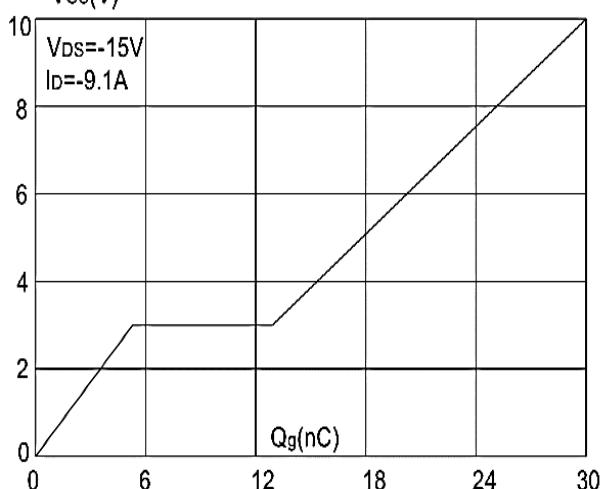


Figure 5: Gate Charge Characteristics

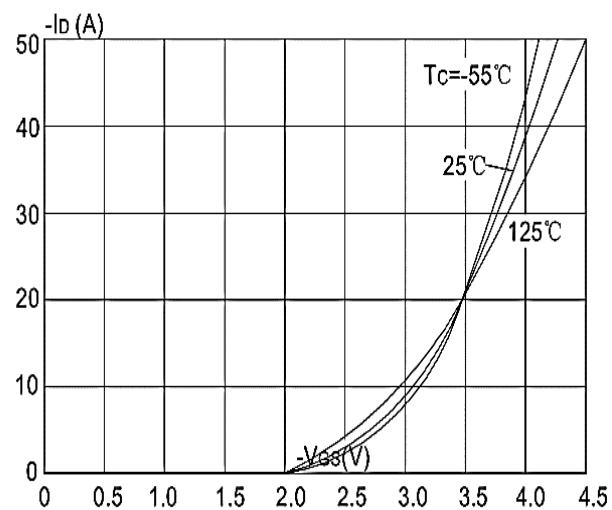


Figure 2: Typical Transfer Characteristics

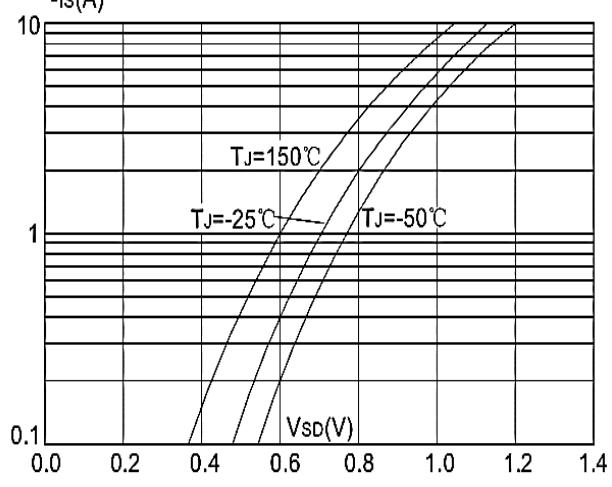


Figure 4: Body Diode Characteristics

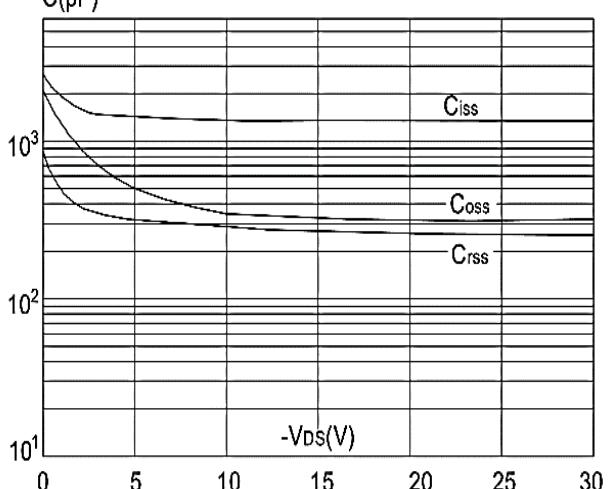


Figure 6: Capacitance Characteristics

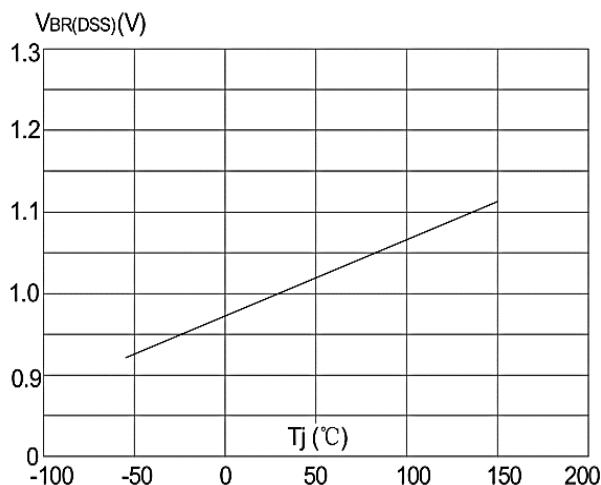


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

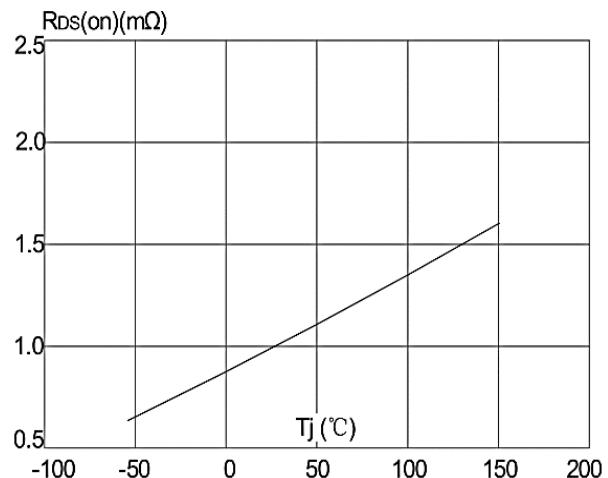


Figure 8: Normalized on Resistance vs. Junction Temperature

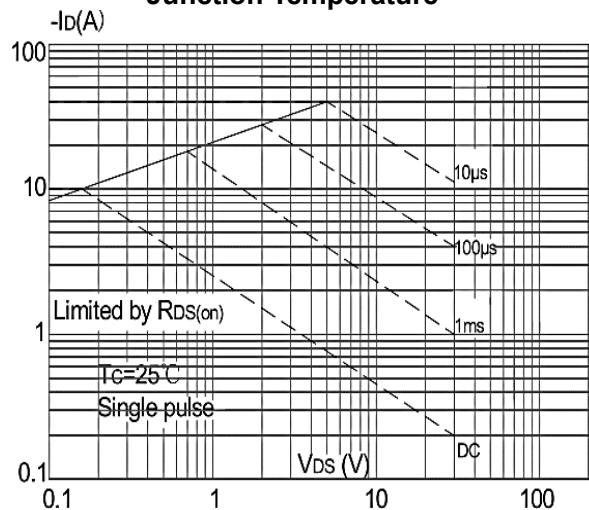


Figure 9: Maximum Safe Operating Area

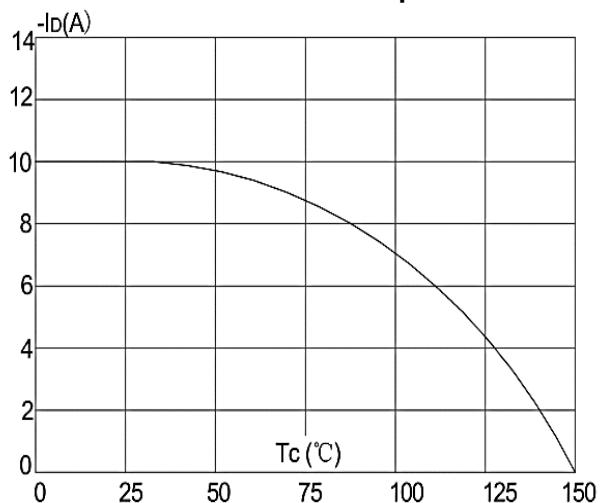


Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature

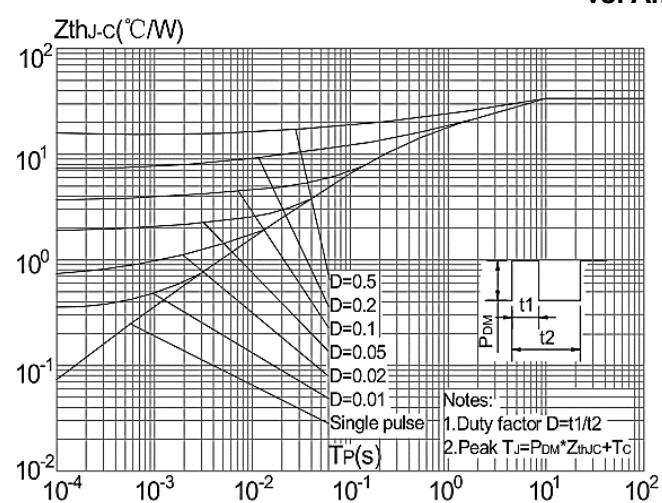
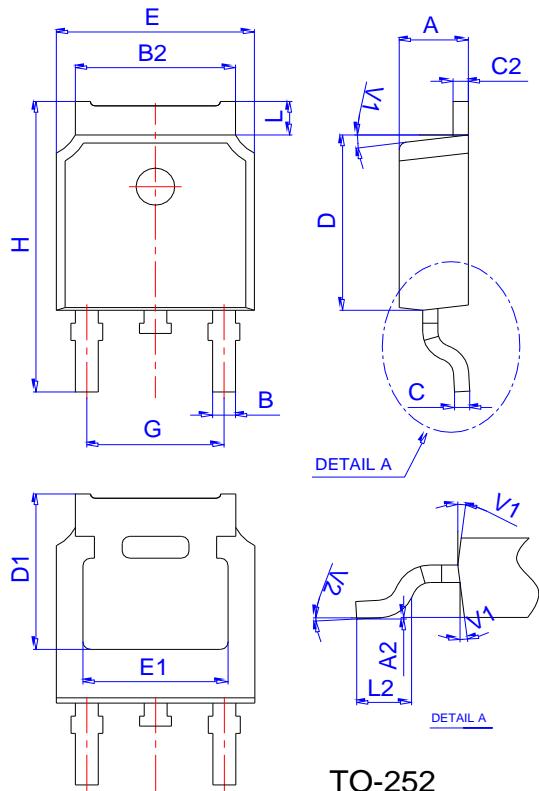


Figure 11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

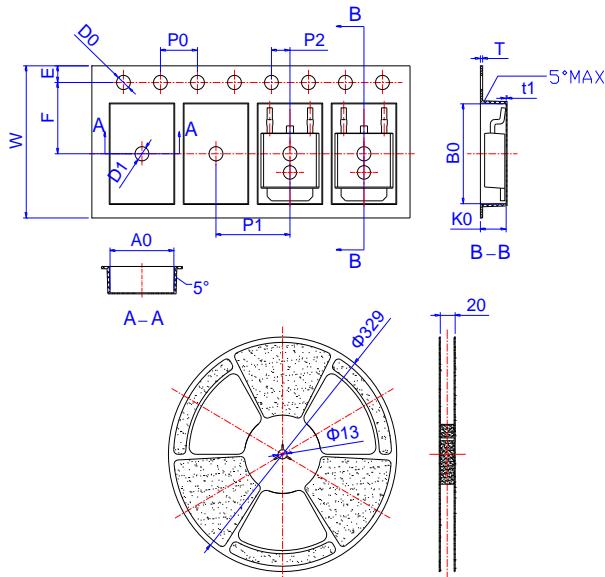
Package Mechanical Data:TO-252-3L



TO-252

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2		0°		6°	0°	6°

Reel Specification-TO-252



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	6.85	6.90	7.00	0.270	0.271	0.276
B0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.105	0.109	0.113
T	0.24			0.027	0.009	
t1	0.10				0.004	
10P0	39.80	40.00	40.20	1.567	1.575	1.583